BIC Simulation Meeting

## **BIC SciFi/Pb Simulation Updates**



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# **Input: Attenuation Measurement**

Measured attenuation dependencies for different naked fibers measured



$$
I(\Delta) = I_0(\alpha e^{\Delta/\lambda_1} + (1 - \alpha)e^{\Delta/\lambda_2})
$$



From measurements at Uni Regina

## **Input: Flat (Old) Optical Connection Improvement**

### N of phe/GeV for different fiber types



- Nb of photelectrons/GeV corrected for attenuation from Baby BCal Hall D measurement [phe/GeV]: **1100**
	- Improvement factor from new family SiPMs from improvement in PDE: **1.5**
	- **Improvement factor from optical connection: 1.16**
	- Attenuation dependence from Old Kuraray Fiber (GlueX Double Clad) anchored to 1914 phe/GeV at  $d = 0$  cm

## **Input: Realistic (New) Optical Connection Improvement**

### Nphe/GeV has been extracted from Baby BCAL measurement with electron shower

- It means that the effective number of phe/GeV = 1100 phe/GeV has **folded in the efficiencies of light guides (LG)** that the measurement has been done with
- Since the number has been **extracted from electron showers**, **different layers (and LG efficiencies) contributed with different weights to this number** following the shower profile
- **Effective number of phe/GeV** with folded LG efficiencies **depends on layer number** (because LG efficiencies differ with layers)

 $0.1\,$ 

2

• Optical Connection improvement factor also depends on the layer

#### **LG efficiencies from Tegan and weighted average with electron shower weights**



Layer



**Electron shower profile weights**



4

10

8

## **Input: Realistic (New) Optical Connection Improvement**

To calculate the layer-dependent improvement factors

- Take simulated LG efficiencies for Baby BCAL (2 scenarios: old (Geant3, Elton), new (Geant4, Tegan)
- Calculate weighted LG efficiency with electron shower weights that the 1100 phe/GeV has been effectively measured with
	- **– new (Geant4, Tegan): 0.565, old (Geant3, Elton): 0.648**
- Calculate relative improvement factor for every BIC layer wrt the weighted average from the point above
	- This gives effective nphe/GeV dependence for each layer





#### **New Improvement factor Relative Improvement factor to the old one (1.16)**

## **Input: Flat (Old) Optical Connection Improvement**



Nb of photelectrons/GeV corrected for attenuation from Baby BCal Hall D measurement [phe/GeV]: **1100** 

### **improvement factor for LG efficiency for every layer**

Geant3 LG efficiencies used (conservative choice)

Improvement factor from new family SiPMs from improvement in PDE: **1.5** 



Number of Photoelectrons for GX - Raw

4000

 $200$ 

son.

2000

noor

4000

Layer 3

÷  $\overline{\mathcal{P}}$  $40$ 

 $20 30$  $40$ 

Nohe

Layer 9

Nobe

Lavor 12

Nobe

Layer 6

mphe e-going end (raw)

nphe p-going end (raw

Max Bin e-going end

Max Bin p-going end

note e-going end (raw

nphe p-going end (raw

Max Bin e-going end

Max Bin p-going end

nphe e-going end (raw)

nphe p-going end (raw)

Max Bin e-going end

Max Bin p-going end

nphe e-going end (raw)

nohe p-going end (raw

Max Bin e-going end

Max Bin p-going end

 $\frac{1}{20}$ 



#### Number of Photoelectrons for L - Raw



**Luxium fiber** 



#### Number of Photoelectrons for NKD - Poisson

Number of Photoelectrons for NKD - Raw



**Double Clad Kuraray** fiber

Nohe



Nphe

Nphe

Number of Photoelectrons for NKS - Poisson

Number of Photoelectrons for NKS - Raw



**Single Clad Kuraray** fiber



Note: This is MPV position (we need to cut below to register the whole MIP peak)

- L Luxium
- GX Old **GlueX**
- NKS Kuraray Single
- NKD Kuraray Double



#### Number of Photoelectrons for GX - Poisson

Number of Photoelectrons for GX - Raw



Old GlueX fiber



Nphe

#### Number of Photoelectrons for L - Poisson

Nphe

Nphe

Number of Photoelectrons for L - Raw

Layer 2

Laver<sub>1</sub>

Laver 3

Nobe

Laver 6

Nobe

Layer 9

nohe e-going end (raw)

nphe p-going end (raw)

- Max Bin e-going end

.... May Rin n-noing end

many nphe e-going end (raw)

nohe e-going end (raw

nphe p-going end (raw

Max Bin e-going end

Max Bin p-going end

mphe e-going end (raw)

nphe p-going end (raw)

--- Max Bin p-going end

Max Bin e-going end

 $\dot{v}$ 

Nobe

Layer 12

nohe p-going end (raw

Max Bin e-going end

Max Bin p-going end



#### Number of Photoelectrons for NKD - Poisson

Number of Photoelectrons for NKD - Raw



**Double Clad Kuraray** fiber



#### Number of Photoelectrons for NKS - Poisson

#### Number of Photoelectrons for NKS - Raw



**Single Clad Kuraray** fiber



# **Backup**

# **Photoelectron statistics** 2023 Hall D, Baby BCal, 3.9 GeV e<sup>+</sup>

From our 2023 Hall D tests using GlueX SiPMs and double-clad Kuraray fibers: **1000 phe/GeV** per side for showers at the center of the Baby BCAL prototype

- Corrected for attenuation: **1100 phe/GeV**\* per side

We can scale these results for the **ePIC Barrel ECal\*:**

- x 1.5 factor improvement in **SiPM photon detection efficiency**
- x 1.16 factor to account for **better optical coupling**
- x 0.69 reduction accounting for **single-clad** Kuraray fibers

This gives ~ **1239 phe/GeV** per side (fully corrected for attenuation)

- **● 10 GeV ɣ at η ~ -1.7:** 5560 phe → **9.8 % max SiPM occupancy**
- **● 19 GeV e- at η ~ -1.7:** 9181 phe → **16.1 % max SiPM occupancy**
- **50 GeV e- at η ~ 1.4 (most extreme case):** 17456 phe → **30.1% max SiPM occupancy**

Well below the region where large nonlinearities in the SiPM response are expected in almost all cases.

Small non-linear effects possible for some ultra-high energy electrons, which is acceptable (e-π separation straightforward).

\* See backup slide for the attenuation length measurement and extraction of those factors





Fig. 16. The number of photoelectrons per GeV per end of the BCAL module is shown as a function of energy. A one parameter fit is plotted (dashed line). For more details see the text.